# NZ3FxxxT1G Series, SZNZ3FxxxT1G Series

# **Zener Voltage Regulators**

# 800 mW SOD-323FL Surface Mount

This series of Zener diodes is packaged in a SOD-323FL surface mount package that has a power dissipation of 800 mW. They are designed to provide voltage regulation protection and are especially attractive in situations where space is at a premium. They are well suited for applications such as cellular phones, hand held portables, high density PC boards, and automotive.

### **Specification Features:**

- Standard Zener Breakdown Voltage Range 2.4 V to 75 V
- Steady State Power Rating of 800 mW
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **Mechanical Characteristics:**

CASE: Void-free, Transfer-Molded Plastic

FINISH: All External Surfaces are Corrosion Resistant

#### MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

**LEADS:** Plated with Pb–Sn or Sn Only (Pb–Free) **POLARITY:** Cathode Indicated by Polarity Band

FLAMMABILITY RATING: UL 94 V-0

**MOUNTING POSITION:** Any

#### **MAXIMUM RATINGS**

Rating	Symbol	Max	Unit
Total Device Dissipation FR-4 Board, (Note 1) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	800 6.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	156	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-4 printed circuit board, single-sided copper, mounting pad 1 cm<sup>2</sup>.



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SOD-323FL CASE 477AC



#### MARKING DIAGRAM



XX = Specific Device CodeM Date Code

#### ORDERING INFORMATION

Device	Package	Shipping†
NZ3FxxxT1G	SOD-323FL (Pb-Free)	3,000 / Tape & Reel
SZNZ3FxxxT1G	SOD-323FL (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

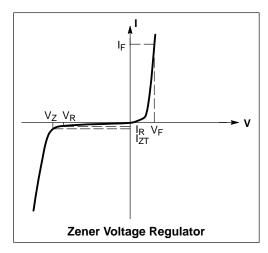
#### **DEVICE MARKING INFORMATION**

See specific marking information in the device marking column of the Electrical Characteristics table on page 2 of this data sheet.

# NZ3FxxxT1G Series, SZNZ3FxxxT1G Series

#### **ELECTRICAL CHARACTERISTICS**

Symbol	Parameter					
VZ	Reverse Zener Voltage @ I <sub>ZT</sub>					
I <sub>ZT</sub>	Reverse Current					
Z <sub>ZT</sub>	Maximum Zener Impedance @ I <sub>ZT</sub>					
I <sub>ZK</sub>	Reverse Current					
Z <sub>ZK</sub>	Maximum Zener Impedance @ I <sub>ZK</sub>					
I <sub>R</sub>	Reverse Leakage Current @ V <sub>R</sub>					
$V_R$	Reverse Voltage					
I <sub>F</sub>	Forward Current					
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>					
$\Theta V_Z$	Maximum Temperature Coefficient of V <sub>Z</sub>					
С	Max. Capacitance @V <sub>R</sub> = 0 and f = 1 MHz					



**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$  unless otherwise noted,  $V_F = 1.3 \text{ V Max.}$  @  $I_F = 10 \text{ mA}$  for all types)

		Zer	er Volta	i <b>ge</b> (No	te 2)	Zene	r Imped	lance	Leakage	Current	Θ'	С					
	Device	\	Z (Volts	s)	@ I <sub>ZT</sub>	Z <sub>ZT</sub> @ I <sub>ZT</sub>	Z <sub>ZK</sub> @ I <sub>ZK</sub>				Z <sub>ZK</sub> @ I <sub>ZK</sub> I <sub>R</sub> @ V <sub>R</sub>		(mV/k) @ I <sub>ZT</sub>		(mV/k)		@ V <sub>R</sub> = 0 f = 1 MHz
Device*	Marking	Min	Nom	Max	mA	Ω	Ω	mA	μА	Volts	Min	Max	pF				
NZ3F2V4T1G		2.2	2.4	2.6	5	120	1000	0.5	50	1.0	-3.5	0	450				
NZ3F4V7T1G		4.4	4.7	5.0	5	100	800	0.5	3	2.0	-3.5	0.2	260				
NZ3F5V1T1G		4.8	5.1	5.4	5	80	500	0.5	2	2.0	-2.7	1.2	225				
NZ3F5V6T1G		5.2	5.6	6.0	5	60	200	0.5	1	2.0	-2.0	2.5	200				
NZ3F9V1T1G		8.5	9.1	9.6	5	45	240	0.5	0.2	7.0	3.8	7.0	130				
NZ3F10VT1G		9.4	10	10.6	5	40	175	0.5	0.1	8.0	4.5	8.0	130				
NZ3F12VT1G		11.4	12	12.7	5	60	220	0.5	0.1	8.0	6.0	10	130				
NZ3F15VT1G		14.3	15	15.8	5	100	220	0.5	0.05	10.5	9.2	13	110				
NZ3F18VT1G		16.8	18	19.1	5	60	290	0.5	0.05	12.6	12.4	16	100				
NZ3F33VT1G		31	33	35	2	140	310	0.5	0.05	23.2	27.4	33.4	70				
NZ3F47VT1G		44	47	50	2	150	500	0.5	0.05	32.9	42.0	51.8	40				
NZ3F75VT1G		70	75	79	2	155	780	0.5	0.05	52.5	73.4	88.6	35				

<sup>\*</sup>Includes SZ-prefix devices where applicable.

### **TYPICAL CHARACTERISTICS**

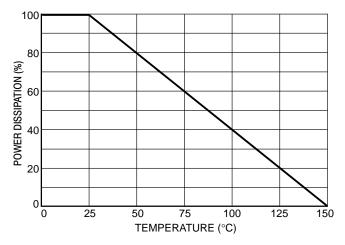


Figure 1. Steady State Power Derating

<sup>2.</sup> Zener voltage is measured with a pulse test current  $I_Z$  at an ambient temperature of 25°C.

# **MECHANICAL CASE OUTLINE**

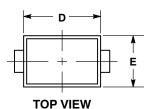
**PACKAGE DIMENSIONS** 



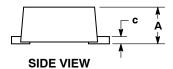


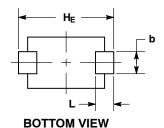
SOD-323FL CASE 477AC **ISSUE B** 

**DATE 12 JAN 2016** 

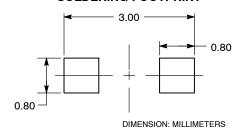








# **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### NOTES:

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- 3.
- LEAD THICKNESS INCLUDES LEAD FINISH.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS					
DIM	MIN	MAX				
Α	0.90	1.08				
A1		0.10				
b	0.50	0.70				
С	0.10	0.25				
D	2.00	2.20				
E	1.30	1.60				
HE	2.40	2.80				
L	0.35	0.65				

### **GENERIC MARKING DIAGRAM\***



= Specific Device Code XX М Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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DESCRIPTION:	SOD-323FL		PAGE 1 OF 1		

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